

## HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPES
- HIGH VOLTAGE CAPABILITY
- VERY HIGH SWITCHING SPEED
- LOW BASE-DRIVE REQUIREMENTS
- U.L. RECOGNISED ISOWATT218 PACKAGE  
(U.L. FILE # E81734 (N))

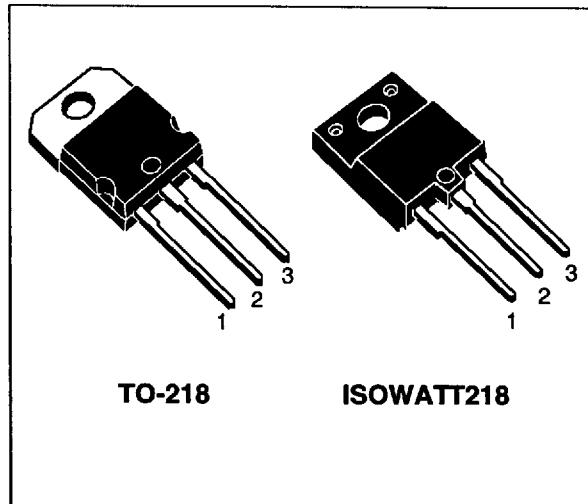
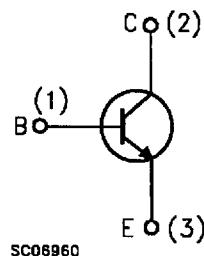
**APPLICATIONS:**

- SWITCH MODE POWER SUPPLIES
- HORIZONTAL DEFLECTION FOR COLOUR  
TVS AND MONITORS

**DESCRIPTION**

The SGSF464 and SGSIF464 are manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.

The SGSF series is designed for high speed switching applications such as power supplies and horizontal deflection circuits in TVs and monitors.


**TO-218                    ISOWATT218**
**INTERNAL SCHEMATIC DIAGRAM**


SC06960

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-Emitter Voltage ( $V_{BE} = 0$ )	1200	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	600	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	7	V
$I_C$	Collector Current	10	A
$I_{CM}$	Collector Peak Current ( $t_p < 5$ ms)	15	A
$I_B$	Base Current	7	A
$I_{BM}$	Base Peak Current ( $t_p < 5$ ms)	12	A
$P_{tot}$	Total Dissipation at $T_c = 25$ °C	125	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

# SGSF464/SGSIF464

## THERMAL DATA

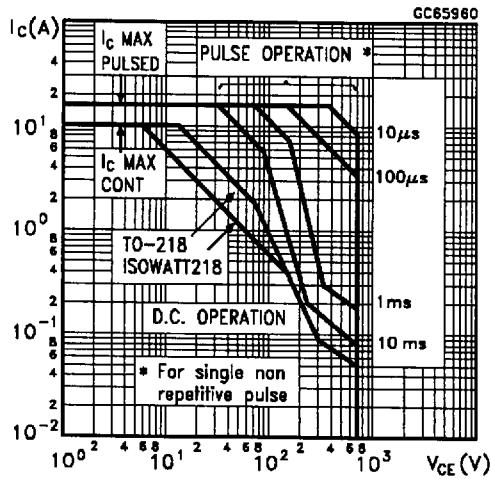
			TO-218	ISOWATT218	
R <sub>thj-case</sub>	Thermal Resistance Junction-Case	Max	1	2.2	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-Ambient	Max	30		°C/W

## ELECTRICAL CHARACTERISTICS ( $T_{case} = 25^\circ\text{C}$ unless otherwise specified)

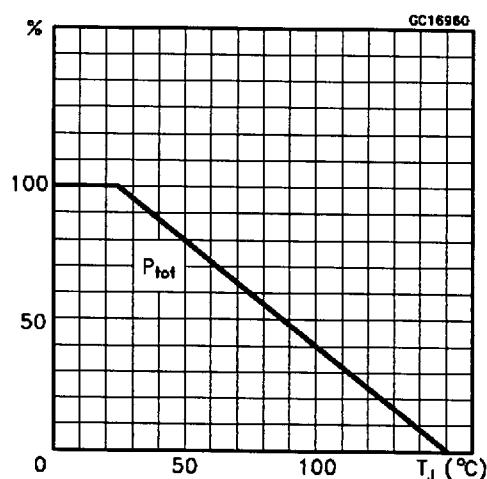
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current ( $V_{BE} = 0$ )	$V_{CE} = 1200 \text{ V}$			200	μA
I <sub>CEO</sub>	Collector Cut-off Current ( $I_B = 0$ )	$V_{EC} = 380 \text{ V}$ $V_{EC} = 600 \text{ V}$			200 2	μA mA
I <sub>EBO</sub>	Emitter Cut-off Current ( $I_C = 0$ )	$V_{BE} = 7 \text{ V}$			1	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage	$I_C = 100 \text{ mA}$	600			V
V <sub>C(E)sat*</sub>	Collector-Emitter Saturation Voltage	$I_C = 6 \text{ A} \quad I_B = 1.2 \text{ A}$ $I_C = 3.5 \text{ A} \quad I_B = 0.5 \text{ A}$			1.5 1.5	V
V <sub>BE(sat)*</sub>	Base-Emitter Saturation Voltage	$I_C = 6 \text{ A} \quad I_B = 1.2 \text{ A}$ $I_C = 3.5 \text{ A} \quad I_B = 0.5 \text{ A}$			1.5 1.5	V
t <sub>ON</sub> t <sub>s</sub> t <sub>f</sub>	Turn-on Time Storage Time Fall Time	RESISTIVE LOAD $V_{CC} = 250 \text{ V} \quad I_C = 6 \text{ A}$ $I_{B1} = 1 \text{ A} \quad I_{B1} = -2 \text{ A}$		0.6 2.45 0.12	1.2 3.5 0.4	μs μs μs
t <sub>ON</sub> t <sub>s</sub> t <sub>f</sub>	Turn-on Time Storage Time Fall Time	RESISTIVE LOAD $V_{CC} = 250 \text{ V} \quad I_C = 5 \text{ A}$ $I_{B1} = 1 \text{ A} \quad I_{B1} = -2 \text{ A}$ With Antisaturation Network		0.6 1.7 0.12		μs μs μs
t <sub>ON</sub> t <sub>s</sub> t <sub>f</sub>	Turn-on Time Storage Time Fall Time	RESISTIVE LOAD $V_{CC} = 250 \text{ V} \quad I_C = 5 \text{ A}$ $I_{B1} = 1 \text{ A} \quad V_{BE(\text{off})} = -5 \text{ V}$		0.6 1.3 0.2		μs μs μs
t <sub>s</sub> t <sub>f</sub>	Storage Time Fall Time	INDUCTIVE LOAD $I_C = 5 \text{ A} \quad h_{FE} = 5$ $V_{CL} = 450 \text{ V} \quad V_{BE(\text{off})} = -5 \text{ V}$ $L = 300 \mu\text{H} \quad R_{BB} = 0.8 \Omega$		1.4 0.1	2.8 0.2	μs μs
t <sub>s</sub> t <sub>f</sub>	Storage Time Fall Time	INDUCTIVE LOAD $I_C = 5 \text{ A} \quad h_{FE} = 5$ $V_{CL} = 450 \text{ V} \quad V_{BE(\text{off})} = -5 \text{ V}$ $L = 300 \mu\text{H} \quad R_{BB} = 0.8 \Omega$ $T_c = 100^\circ\text{C}$			4 0.3	μs μs

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

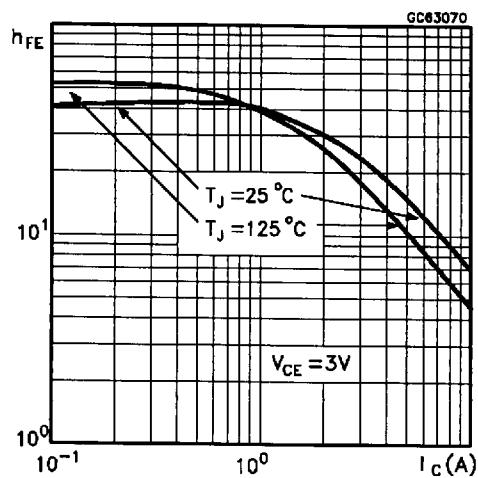
Safe Operating Area Thermal Impedance



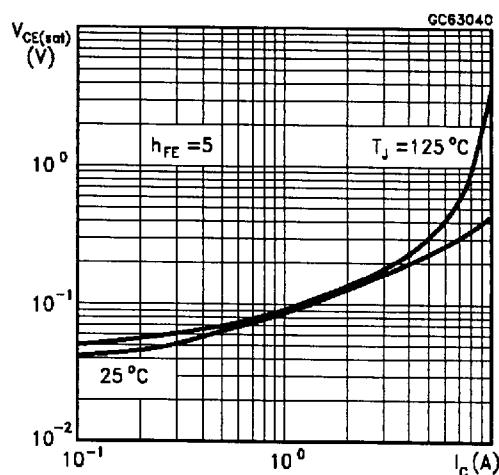
Derating Curve



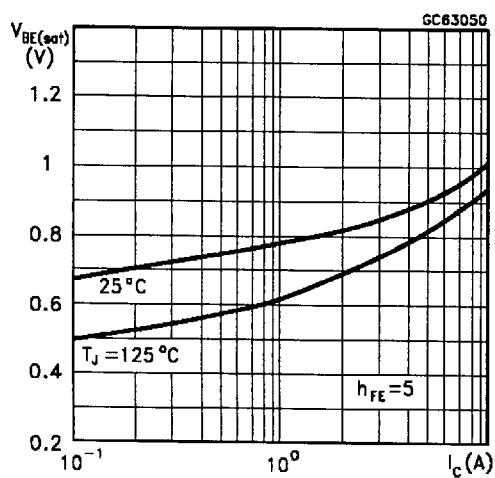
DC Current Gain



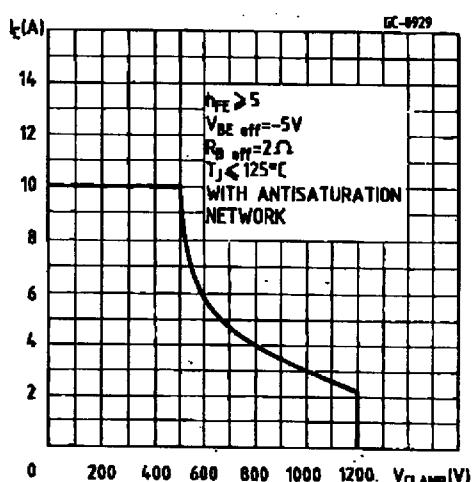
Collector Emitter Saturation Voltage



Base Emitter Saturation Voltage

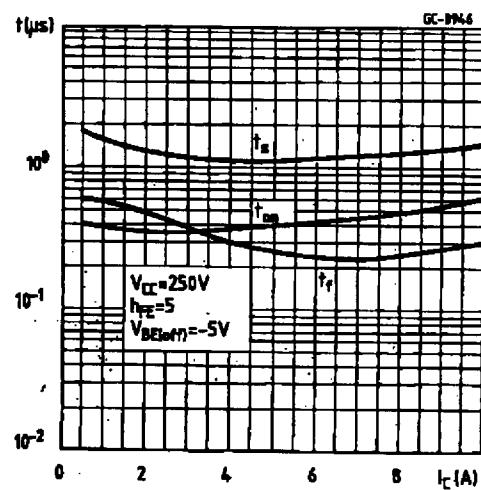


Reverse Biased SOA

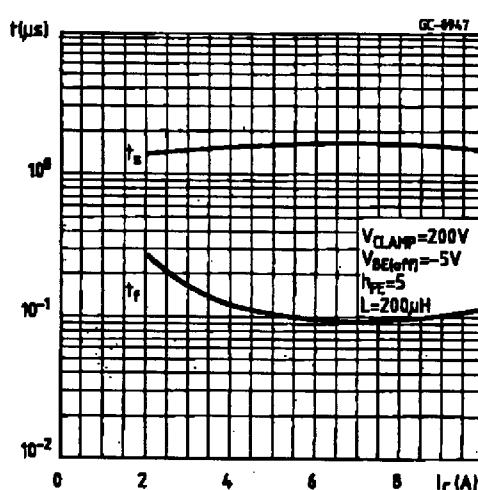


## SGSF464/SGSIF464

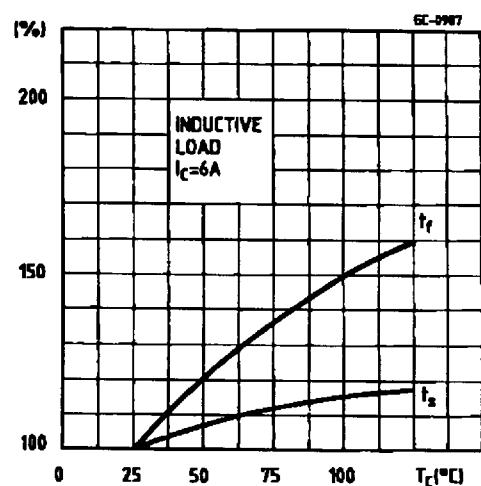
Resistive Load Switching Times



Resistive Load Switching Times

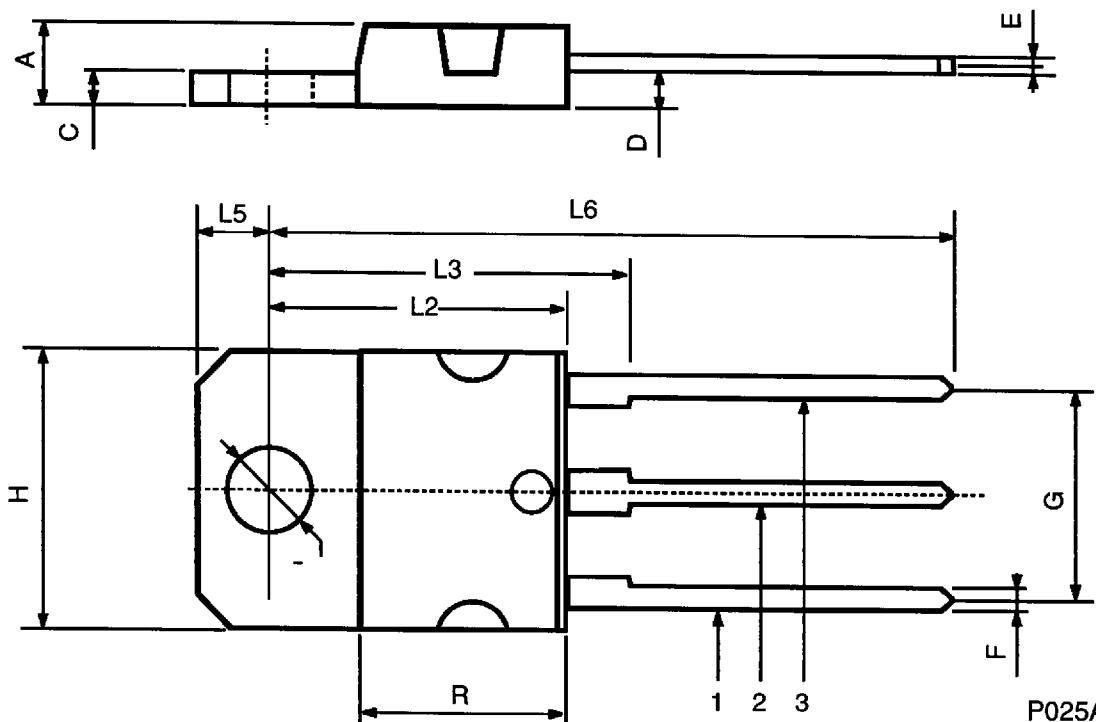


Switching Times Percentage Variation



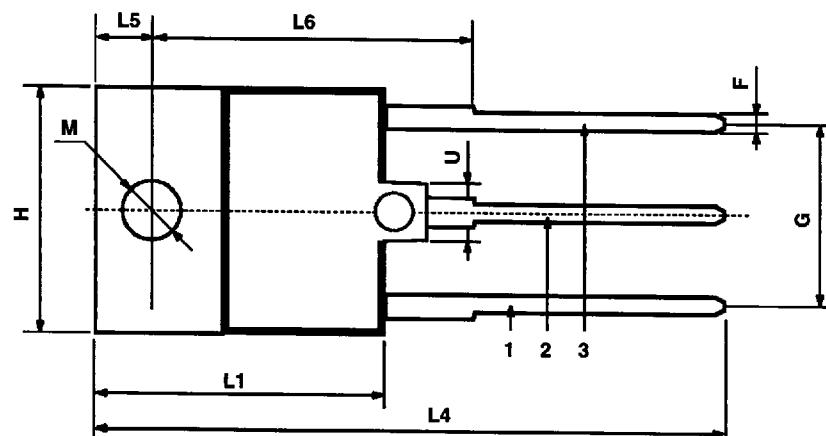
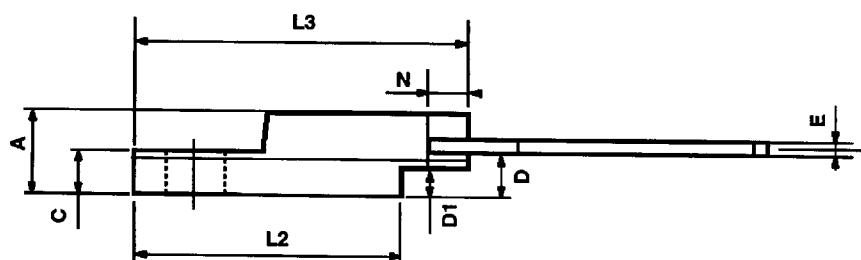
## TO-218 (SOT-93) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.7		4.9	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.5			0.098	
E	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
H	14.7		15.2	0.578		0.598
L <sub>2</sub>	-		16.2	-		0.637
L <sub>3</sub>		18			0.708	
L <sub>5</sub>	3.95		4.15	0.155		0.163
L <sub>6</sub>		31			1.220	
R	-		12.2	-		0.480
Ø	4		4.1	0.157		0.161



## ISOWATT218 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.35		5.65	0.210		0.222
C	3.3		3.8	0.130		0.149
D	2.9		3.1	0.114		0.122
D1	1.88		2.08	0.074		0.081
E	0.75		1	0.029		0.039
F	1.05		1.25	0.041		0.049
G	10.8		11.2	0.425		0.441
H	15.8		16.2	0.622		0.637
L1	20.8		21.2	0.818		0.834
L2	19.1		19.9	0.752		0.783
L3	22.8		23.6	0.897		0.929
L4	40.5		42.5	1.594		1.673
L5	4.85		5.25	0.190		0.206
L6	20.25		20.75	0.797		0.817
M	3.5		3.7	0.137		0.145
N	2.1		2.3	0.082		0.090
U		4.6			0.181	



P025C